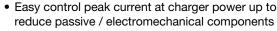


Thyristor High Voltage, Phase Control SCR, 25 A



PRIMARY CHARACTERISTICS						
I _{T(AV)}	16 A					
V_{DRM}/V_{RRM}	1200 V					
V_{TM}	1.25 V					
I _{GT}	45 mA					
T_J	-40 °C to +125 °C					
Package	TO-220AB					
Circuit configuration	Single SCR					

FEATURES





· Meets JESD 201 class 1A whisker test

Flexible solution for reliable AC power rectification

COMPLIANT HALOGEN FREE

- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- On-board and off-board EV/HEV battery chargers
- Renewable energy inverters

DESCRIPTION

The VS-25TTS12HM3 high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications.

OUTPUT CURRENT IN TYPICAL APPLICATIONS								
APPLICATIONS SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS								
Capacitive input filter T _A = 55 °C, T _J = 125 °C, common heatsink of 1 °C/W	18	22	А					

MAJOR RATINGS AND CHARACTERISTICS							
PARAMETER	TEST CONDITIONS	VALUES	UNITS				
I _{T(AV)}	Sinusoidal waveform	16	Α				
I _{RMS}		25	_ ^				
V_{RRM}/V_{DRM}		1200	V				
I _{TSM}		320	Α				
V _T	16 A, T _J = 25 °C	1.25	V				
dV/dt		500	V/µs				
dl/dt		150	A/μs				
T _J		-40 to +125	°C				

VOLTAGE RATINGS								
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{DRM} , MAXIMUM PEAK DIRECT VOLTAGE V	I _{RRM} /I _{DRM} AT 125 °C mA					
VS-25TTS12HM3	1200	1200	10					



ABSOLUTE MAXIMUM RATINGS													
DADAMETED	SYMBOL	TECT OO	VAL										
PARAMETER	SYMBOL	TEST CO	TYP.	UNITS									
Maximum average on-state current	I _{T(AV)}	T _C = 93 °C, 180° conduc	tion half sine wave	1	6								
Maximum RMS on-state current	I _{RMS}			2	5	Α							
Maximum peak, one-cycle,		10 ms sine pulse, rated \	10 ms sine pulse, rated V _{RRM} applied		70	A							
non-repetitive surge current	I _{TSM}	10 ms sine pulse, no vol	tage reapplied	32	20								
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated \	V _{RRM} applied	36	65	A ² s							
Maximum 1-t for fusing	1-1	10 ms sine pulse, no vol	515		T ALS								
Maximum I ² √t for fusing	I ² √t	t = 0.1 to 10 ms, no volta	age reapplied	51	52	A²√s							
Maximum on-state voltage drop	V_{TM}	16 A, T _J = 25 °C		1.:	25	V							
On-state slope resistance	r _t	r_t $T_1 = 125 ^{\circ}C$		2.0	mΩ								
Threshold voltage	V _{T(TO)}	1J = 123 C		1.0		V							
Maximum reverse and direct leakage	1 /1	T _J = 25 °C	\/ - rotod \/ \/ \/	0	.5								
current	I _{RM} /I _{DM}	T _J = 125 °C	$V_R = \text{rated } V_{RRM}/V_{DRM}$		0								
Holding current	I _H	Anode supply = 6 V, resistive load, initial I_T = 1 A, T_J = 25 °C		-	150	mA							
Maximum latching current	ΙL	Anode supply = 6 V, resistive load, T _J = 25 °C			Anode supply = 6 V, resistive load, T _J = 25 °C		Anode supply = 6 V, resistive load, T _J = 25 °C		Anode supply = 6 V, resistive load, T _J = 25 °C		20	00	
Maximum rate of rise of off-state voltage	dV/dt	$T_J = T_J \text{ max., linear to } 80 \text{ °C, } V_{DRM} = R_q - k = \text{open}$			00	V/µs							
Maximum rate of rise of turned-on current	dl/dt		15	50	A/µs								

TRIGGERING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum peak gate power	P _{GM}		8.0	W
Maximum average gate power	P _{G(AV)}		2.0	VV
Maximum peak positive gate current	+I _{GM}		1.5	Α
Maximum peak negative gate voltage	-V _{GM}		10	V
Marian and PO and a model of		Anode supply = 6 V, resistive load, T _J = - 10 °C	60	
Maximum required DC gate current to trigger	I _{GT}	Anode supply = 6 V, resistive load, T _J = 25 °C	45	mA
11995.		Anode supply = 6 V, resistive load, T _J = 125 °C	20	
		Anode supply = 6 V, resistive load, T _J = - 10 °C	2.5	
Maximum required DC gate voltage to trigger	V_{GT}	Anode supply = 6 V, resistive load, T _J = 25 °C 2.0		v
voltage to trigger		Anode supply = 6 V, resistive load, T _J = 125 °C	1.0	V
Maximum DC gate voltage not to trigger	V_{GD}	T 105 °C V reted value	0.25	
Maximum DC gate current not to trigger	I _{GD}	T _J = 125 °C, V _{DRM} = rated value	2.0	mA

SWITCHING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Typical turn-on time	t _{gt}	T _J = 25 °C	0.9	
Typical reverse recovery time	t _{rr}	T _{.1} = 125 °C	4	μs
Typical turn-off time	t _q	1J = 125 C	110	



THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range		T _J , T _{Stg}		-40 to 125	°C		
Maximum thermal resistance, junction to case		R _{thJC}	JC DC operation				
Maximum thermal resistance, junction to ambient		R _{thJA}		62	°C/W		
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.5			
Approximate weight				2	g		
Approximate weight				0.07	OZ.		
Mounting toward	minimum			6 (5)	kgf · cm		
Mounting torque	maximum			12 (10)	(lbf · in)		
Marking device			Case style TO-220AB	25TT	S12H		

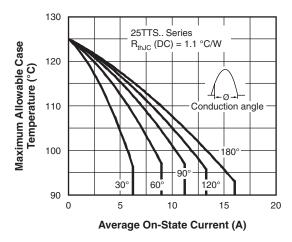


Fig. 1 - Current Rating Characteristics

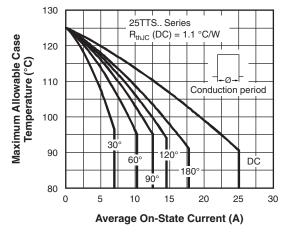


Fig. 2 - Current Rating Characteristics

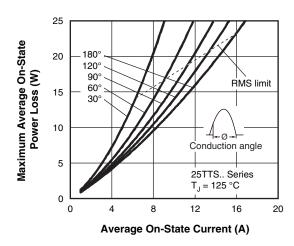


Fig. 3 - On-State Power Loss Characteristics

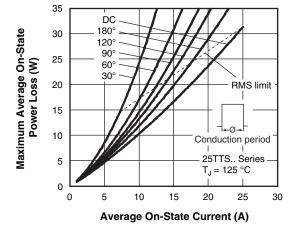


Fig. 4 - On-State Power Loss Characteristics



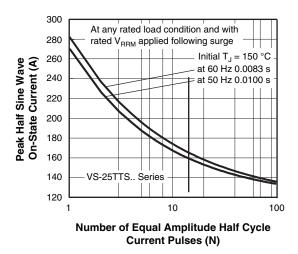


Fig. 5 - Maximum Non-Repetitive Surge Current

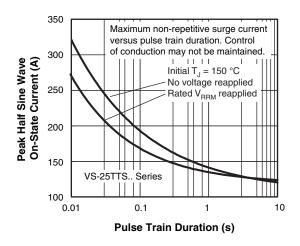


Fig. 6 - Maximum Non-Repetitive Surge Current

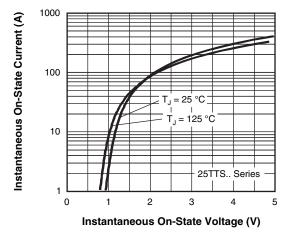


Fig. 7 - On-State Voltage Drop Characteristics

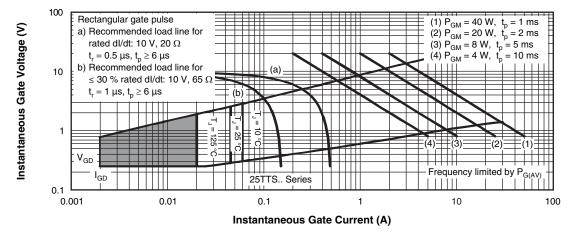


Fig. 8 - Gate Characteristics



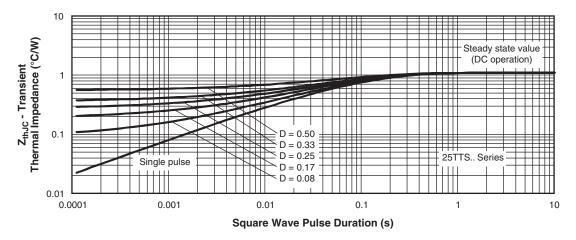
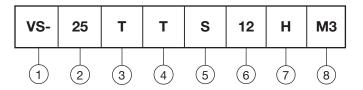


Fig. 9 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

Device code



- Vishay Semiconductors product
- **2** Current rating (25 = 25 A)
- 3 Circuit configuration:

T = single thyristor

- 4 Package:
 - T = TO-220AB
- 5 Type of silicon:
 - S = standard recovery rectifier
- 6 Voltage rating 12 = 1200 V
- 7 H = AEC-Q101 qualified
- 8 Environmental digit:

M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

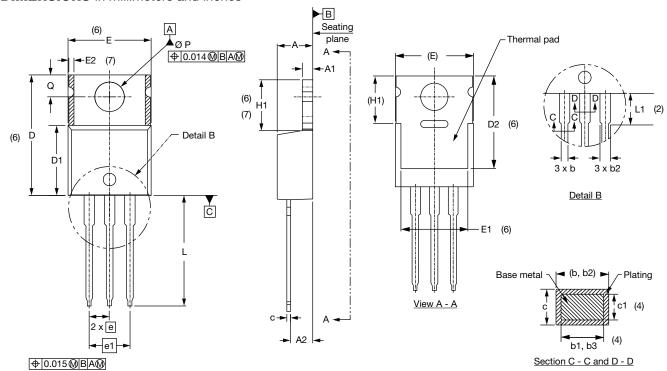
ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-25TTS12HM3	50	1000	Antistatic plastic tubes				

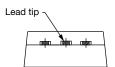
LINKS TO RELATED DOCUMENTS						
Dimensions <u>www.vishay.com/doc?95222</u>						
Part marking information	www.vishay.com/doc?95028					



TO-220AB

DIMENSIONS in millimeters and inches





Conforms to JEDEC® outline TO-220AB

SYMBOL	MILLIMETERS		INC	INCHES		NOTES	SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183			D2	11.68	12.88	0.460	0.507	6
A1	1.14	1.40	0.045	0.055			Е	10.11	10.51	0.398	0.414	3, 6
A2	2.56	2.92	0.101	0.115			E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040			E2	ı	0.76	-	0.030	7
b1	0.38	0.97	0.015	0.038	4		е	2.41	2.67	0.095	0.105	
b2	1.20	1.73	0.047	0.068			e1	4.88	5.28	0.192	0.208	
b3	1.14	1.73	0.045	0.068	4		H1	5.84	6.86	0.230	0.270	6, 7
С	0.36	0.61	0.014	0.024			L	13.52	14.02	0.532	0.552	
c1	0.36	0.56	0.014	0.022	4		L1	3.32	3.82	0.131	0.150	2
D	14.85	15.25	0.585	0.600	3		ØР	3.54	3.73	0.139	0.147	
D1	8.38	9.02	0.330	0.355			Q	2.60	3.00	0.102	0.118	

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC® TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline

Revision: 23-Feb-2024 1 Document Number: 95222



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Vishay

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